

Phase Control Thyristor Types N5177FC200 to N5177FC280

Absolute Maximum Ratings

| | VOLTAGE RATINGS | MAXIMUM LIMITS | UNITS |
|-----------|---|----------------|-------|
| V_{DRM} | Repetitive peak off-state voltage, (note 1) | 2000-2800 | V |
| V_{DSM} | Non-repetitive peak off-state voltage, (note 1) | 2000-2800 | V |
| V_{RRM} | Repetitive peak reverse voltage, (note 1) | 2000-2800 | V |
| V_{RSM} | Non-repetitive peak reverse voltage, (note 1) | 2100-2900 | V |

| | OTHER RATINGS | MAXIMUM LIMITS | UNITS |
|---------------|--|-------------------|-------------|
| $I_{T(AV)}$ | Mean on-state current. $T_{sink}=55^{\circ}C$, (note 2) | 5177 | A |
| $I_{T(AV)}$ | Mean on-state current. $T_{sink}=85^{\circ}C$, (note 2) | 3626 | A |
| $I_{T(AV)}$ | Mean on-state current. $T_{sink}=85^{\circ}C$, (note 3) | 2262 | A |
| $I_{T(RMS)}$ | Nominal RMS on-state current. $T_{sink}=25^{\circ}C$, (note 2) | 10109 | A |
| $I_{T(d.c.)}$ | D.C. on-state current. $T_{sink}=25^{\circ}C$, (note 4) | 9033 | A |
| I_{TSM} | Peak non-repetitive surge $t_p=10ms$, $V_{RM}=0.6V_{RRM}$, (note 5) | 67.5 | kA |
| I_{TSM2} | Peak non-repetitive surge $t_p=10ms$, $V_{RM}\leq 10V$, (note 5) | 75 | kA |
| I^2t | I^2t capacity for fusing $t_p=10ms$, $V_{RM}=0.6V_{RRM}$, (note 5) | 22.8×10^6 | A^2s |
| I^2t | I^2t capacity for fusing $t_p=10ms$, $V_{RM}\leq 10V$, (note 5) | 28.1×10^6 | A^2s |
| di_T/dt | Maximum rate of rise of on-state current (repetitive), (Note 6) | 150 | $A/\mu s$ |
| | Maximum rate of rise of on-state current (non-repetitive), (Note 6) | 300 | $A/\mu s$ |
| V_{RGM} | Peak reverse gate voltage | 5 | V |
| $P_{G(AV)}$ | Mean forward gate power | 5 | W |
| P_{GM} | Peak forward gate power | 30 | W |
| V_{GD} | Non-trigger gate voltage, (Note 7) | 0.25 | V |
| T_{HS} | Operating temperature range | -40 to +125 | $^{\circ}C$ |
| T_{stg} | Storage temperature range | -40 to +150 | $^{\circ}C$ |

Notes: -

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, $125^{\circ}C$ T_j initial.
- 6) $V_D=67\% V_{DRM}$, $I_{TM}=4000A$, $I_{FG}=2A$, $t_r\leq 0.5\mu s$, $T_{case}=125^{\circ}C$.
- 7) Rated V_{DRM} .

Characteristics

| | PARAMETER | MIN. | TYP. | MAX. | TEST CONDITIONS (Note 1) | UNITS |
|------------------|--|------|-------|--------|--|-------|
| V _{TM} | Maximum peak on-state voltage | - | - | 1.40 | I _{TM} =6000A | V |
| V ₀ | Threshold voltage | - | - | 0.80 | | V |
| r _S | Slope resistance | - | - | 0.1 | | mΩ |
| dv/dt | Critical rate of rise of off-state voltage | 1000 | - | - | V _D =80% V _{DRM} , Linear ramp, gate o/c | V/μs |
| I _{DRM} | Peak off-state current | - | - | 300 | Rated V _{DRM} | mA |
| I _{RRM} | Peak reverse current | - | - | 300 | Rated V _{RRM} | mA |
| V _{GT} | Gate trigger voltage | - | - | 3.0 | T _j =25°C, V _D =10V, I _T =3A | V |
| I _{GT} | Gate trigger current | - | - | 300 | | mA |
| I _H | Holding current | - | - | 1000 | T _j =25°C | mA |
| t _{gd} | Gate controlled turn-on delay time | - | 1.0 | 2.0 | I _{FG} =2A, t _r =0.5μs, V _D =67%V _{DRM} , I _{TM} =2000A, di/dt=10A/μs, T _j =25°C | μs |
| t _{gt} | Turn-on time | - | 1.5 | 3.0 | | μs |
| Q _{rr} | Recovered Charge | - | 11000 | - | | μC |
| Q _{ra} | Recovered Charge, 50% chord | - | 7250 | 8500 | I _{TM} =4000A, t _p =2ms, di/dt=10A/μs, V _r =50V | μC |
| I _{rm} | Reverse recovery current | - | 275 | - | | A |
| t _{rr} | Reverse recovery time, 50% chord | - | 50 | - | | μs |
| t _q | Turn-off time | - | 400 | - | I _{TM} =4000A, t _p =2ms, di/dt=10A/μs, V _r =50V, V _{dr} =67%V _{DRM} , dV _{dr} /dt=20V/μs | μs |
| | | - | 700 | - | I _{TM} =4000A, t _p =2ms, di/dt=10A/μs, V _r =50V, V _{dr} =67%V _{DRM} , dV _{dr} /dt=200V/μs | |
| R _θ | Thermal resistance, junction to heatsink | - | - | 0.0065 | Double side cooled | K/W |
| | | - | - | 0.013 | Single side cooled | K/W |
| F | Mounting force | 81 | - | 99 | | kN |
| W _t | Weight | - | 2.8 | - | | kg |

Notes: -

1) Unless otherwise indicated T_j=125°C.

Notes on Ratings and Characteristics**1.0 Voltage Grade Table**

| Voltage Grade | V_{DRM} V_{DSM} V_{RRM} V | V_{RSM} V | V_D V_R DC V |
|---------------|------------------------------------|----------------|---------------------|
| 20 | 2000 | 2100 | 1250 |
| 22 | 2200 | 2300 | 1350 |
| 24 | 2400 | 2500 | 1450 |
| 26 | 2600 | 2700 | 1550 |
| 28 | 2800 | 2900 | 1650 |

2.0 Extension of Voltage Grades

This report is applicable to other and higher voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Repetitive dv/dt

Standard dv/dt is 1000V/μs.

5.0 Computer Modelling Parameters**5.1 Device Dissipation Calculations**

$$I_{AV} = \frac{-V_0 + \sqrt{V_0^2 + 4 \cdot ff \cdot r_s \cdot W_{AV}}}{2 \cdot ff \cdot r_s} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j \max} - T_{Hs}$$

Where $V_0=0.80V$, $r_s=0.10m\Omega$,

R_{th} = Supplementary thermal impedance, see table below.

ff = Form factor, see table below.

| Supplementary Thermal Impedance | | | | | | | |
|---------------------------------|---------|---------|---------|---------|---------|---------|--------|
| Conduction Angle | 30° | 60° | 90° | 120° | 180° | 270° | d.c. |
| Square wave Double Side Cooled | 0.00717 | 0.00707 | 0.00698 | 0.00689 | 0.00673 | 0.00652 | 0.0065 |
| Square wave Single Side Cooled | 0.0137 | 0.01359 | 0.01349 | 0.0134 | 0.01323 | 0.01301 | 0.013 |
| Sine wave Double Side Cooled | 0.00709 | 0.00697 | 0.00687 | 0.00678 | 0.00654 | | |
| Sine wave Single Side Cooled | 0.0136 | 0.01348 | 0.01337 | 0.01328 | 0.01303 | | |

| Form Factors | | | | | | | |
|------------------|------|------|------|------|------|------|------|
| Conduction Angle | 30° | 60° | 90° | 120° | 180° | 270° | d.c. |
| Square wave | 3.46 | 2.45 | 2 | 1.73 | 1.41 | 1.15 | 1 |
| Sine wave | 3.98 | 2.78 | 2.22 | 1.88 | 1.57 | | |

5.2 Calculating V_T using ABCD Coefficients

The on-state characteristic I_T vs. V_T , on page 5 is represented in two ways;

- (i) the well established V_o and r_s tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_T in terms of I_T given below:

$$V_T = A + B \cdot \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_T agree with the true device characteristic over a current range, which is limited to that plotted.

| 25°C Coefficients | | 125°C Coefficients | |
|-------------------|----------------------------|--------------------|----------------------------|
| A | 0.9330324 | A | 0.74051412 |
| B | 0.01656743 | B | 0.01288484 |
| C | 7.79529×10^{-5} | C | 1.0456×10^{-4} |
| D | -1.157992×10^{-3} | D | -1.032364×10^{-3} |

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{-\frac{t}{\tau_p}} \right)$$

Where $p = 1$ to n , n is the number of terms in the series and:

- t = Duration of heating pulse in seconds.
- r_t = Thermal resistance at time t .
- r_p = Amplitude of p_{th} term.
- τ_p = Time Constant of r_{th} term.

| D.C. Double Side Cooled | | | | |
|-------------------------|---------------------------|---------------------------|---------------------------|---------------------------|
| Term | 1 | 2 | 4 | 5 |
| r_p | 3.424745×10^{-3} | 1.745273×10^{-3} | 8.532017×10^{-4} | 3.457329×10^{-4} |
| τ_p | 1.125391 | 0.1878348 | 0.02788979 | 8.430889×10^{-3} |

| D.C. Single Side Cooled | | | | |
|-------------------------|---------------------------|---------------------------|---------------------------|--------------------------|
| Term | 1 | 2 | 5 | 6 |
| r_p | 8.375269×10^{-3} | 2.518437×10^{-3} | 1.193758×10^{-3} | 7.45432×10^{-4} |
| τ_p | 8.929845 | 0.4711304 | 0.08221244 | 0.01221961 |

Curves

Figure 1 - On-state characteristics of Limit device

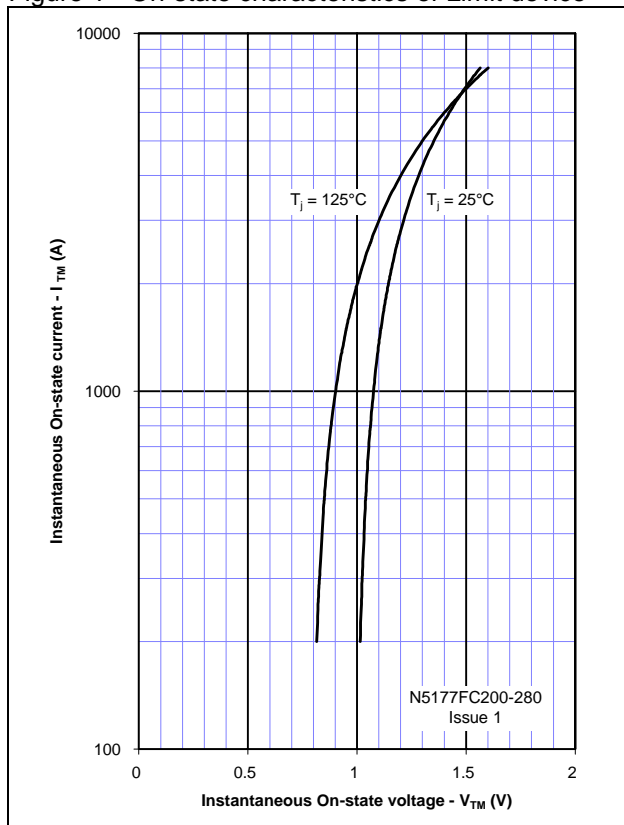


Figure 2 - Transient Thermal Impedance

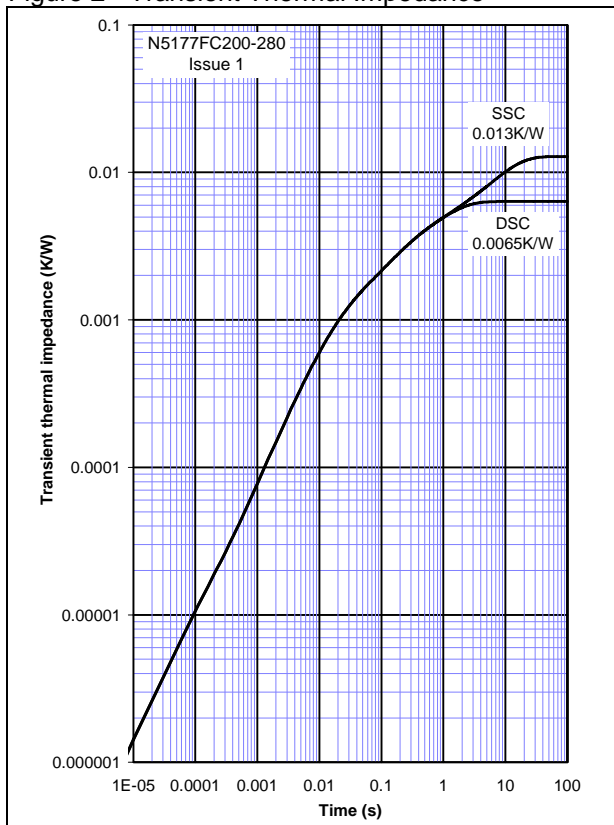


Figure 3 - Gate Characteristics - Trigger Limits

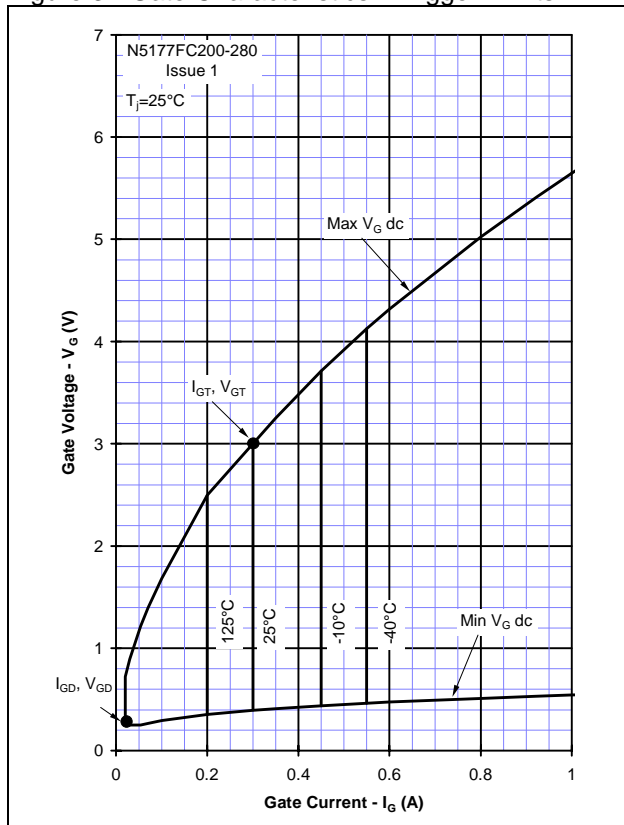


Figure 4 - Gate Characteristics - Power Curves

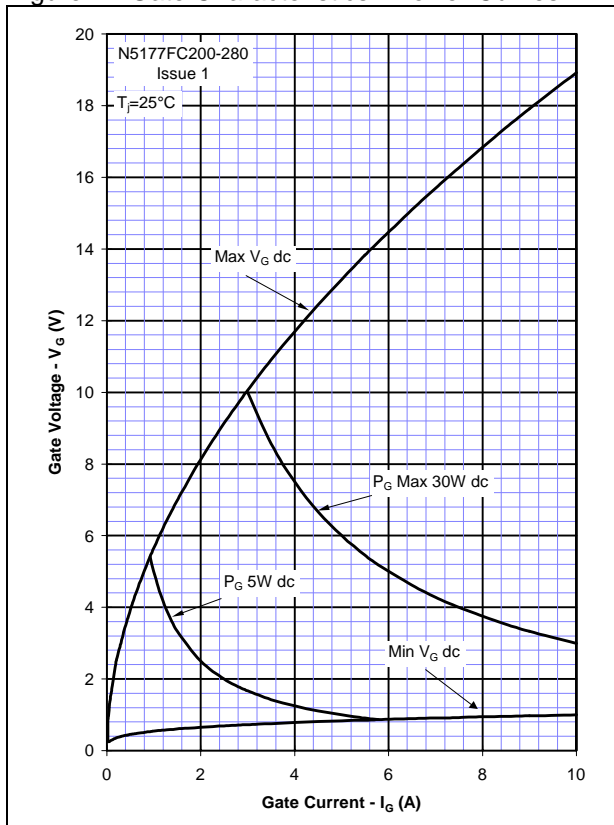


Figure 5 – Recovered Charge, Q_{rr}

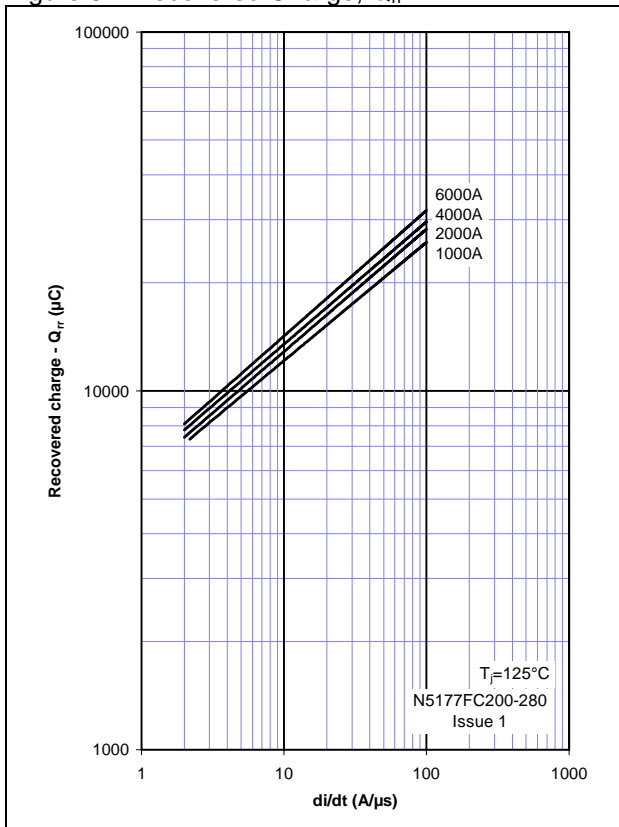


Figure 6 – Recovered charge, Q_{ra} (50% chord)

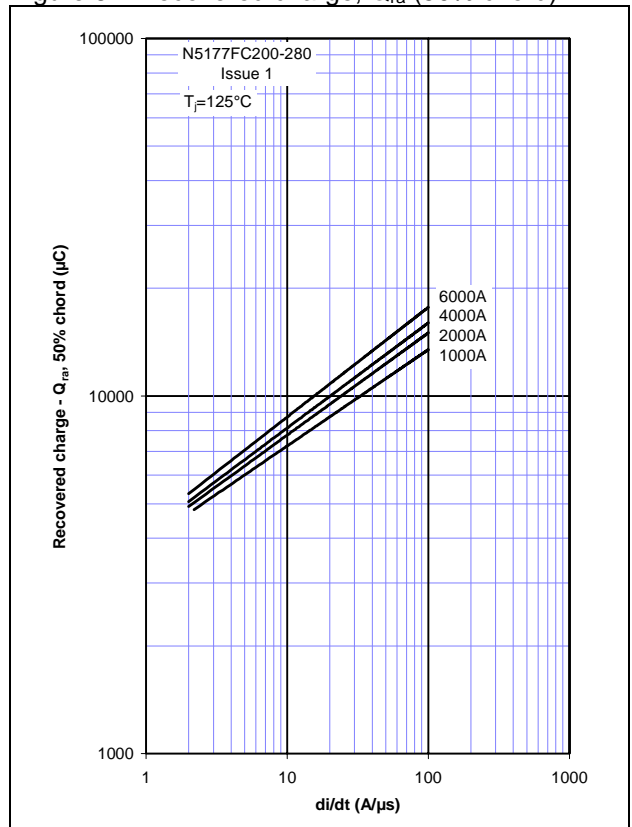


Figure 7 – Reverse recovery current, I_{rm}

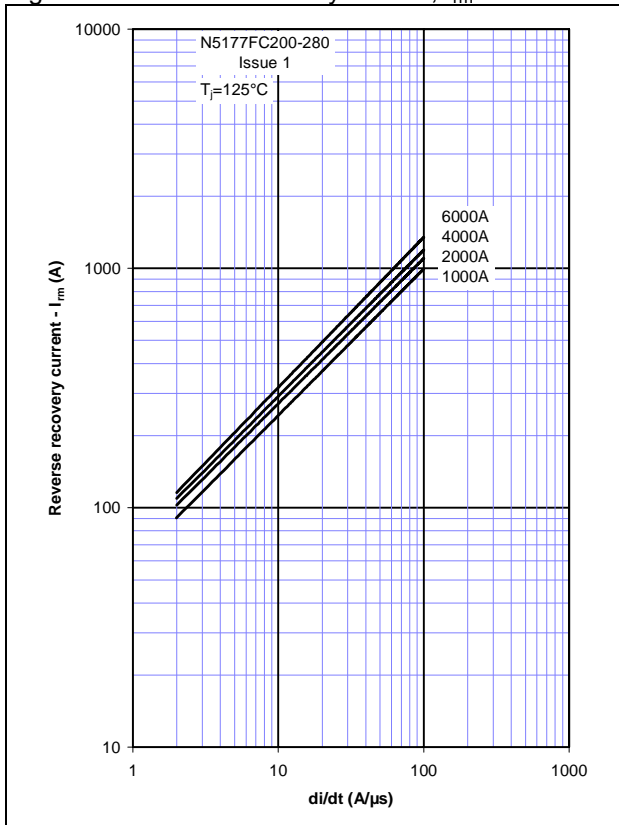


Figure 8 – Reverse recovery time, t_{rr}

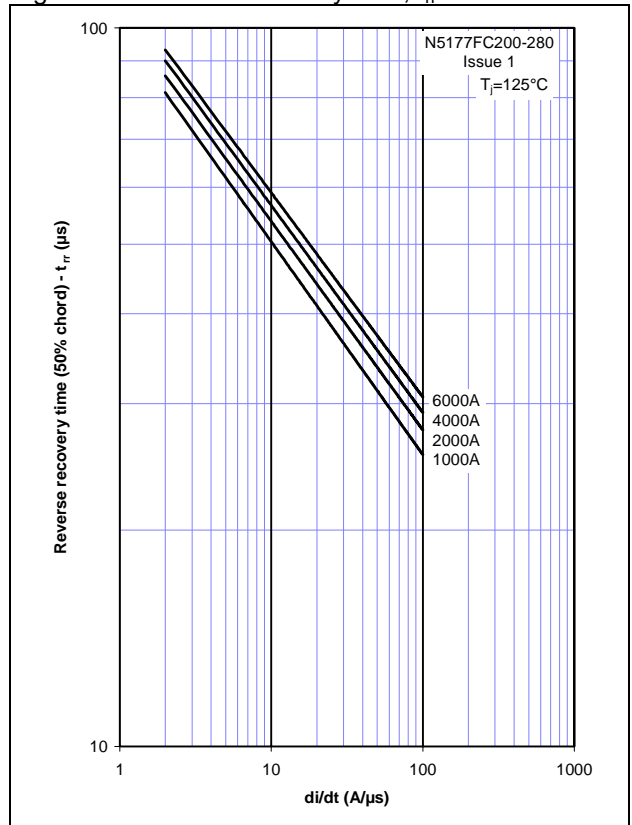


Figure 9 – On-state current vs. Power dissipation – Double Side Cooled (Sine wave)

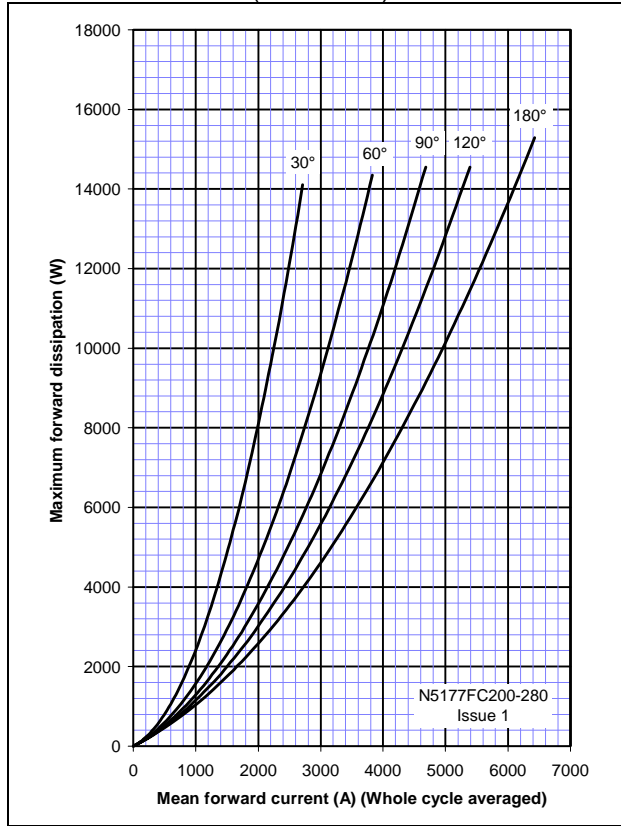


Figure 10 – On-state current vs. Heatsink temperature - Double Side Cooled (Sine wave)

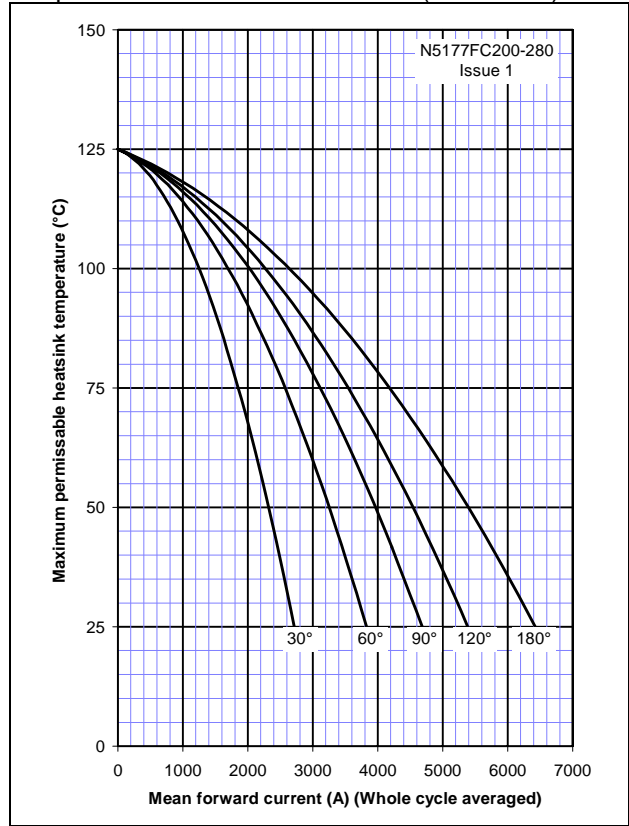


Figure 11 – On-state current vs. Power dissipation – Double Side Cooled (Square wave)

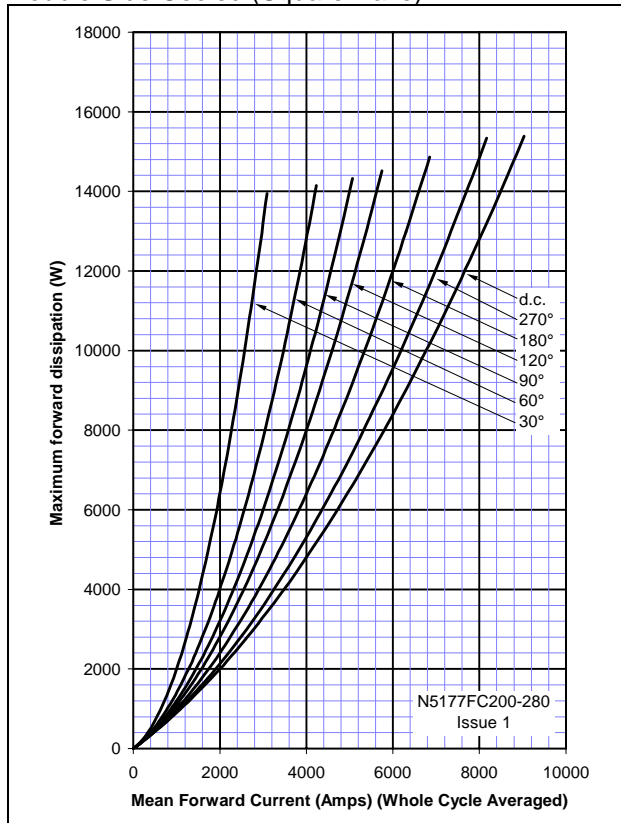


Figure 12 – On-state current vs. Heatsink temperature - Double Side Cooled (Square wave)

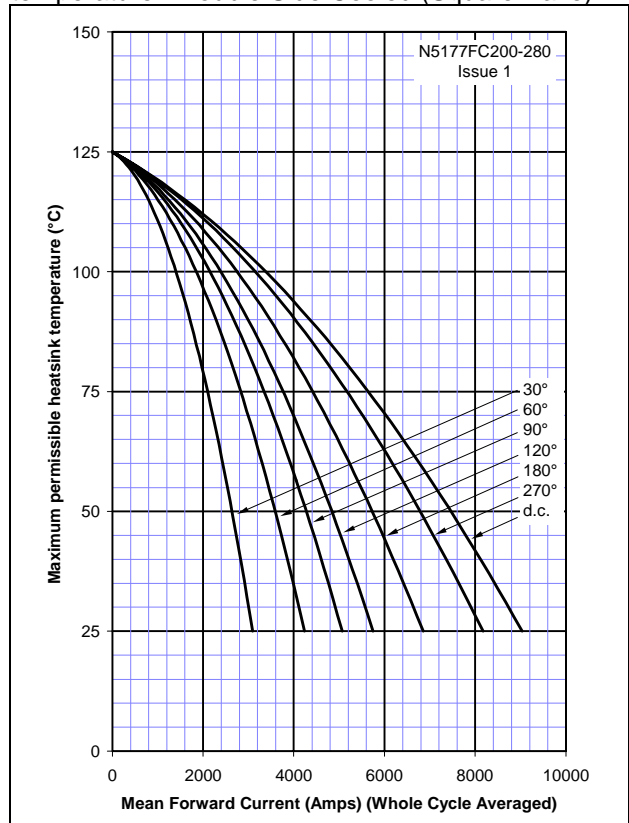


Figure 13 – On-state current vs. Power dissipation – Single Side Cooled (Sine wave)

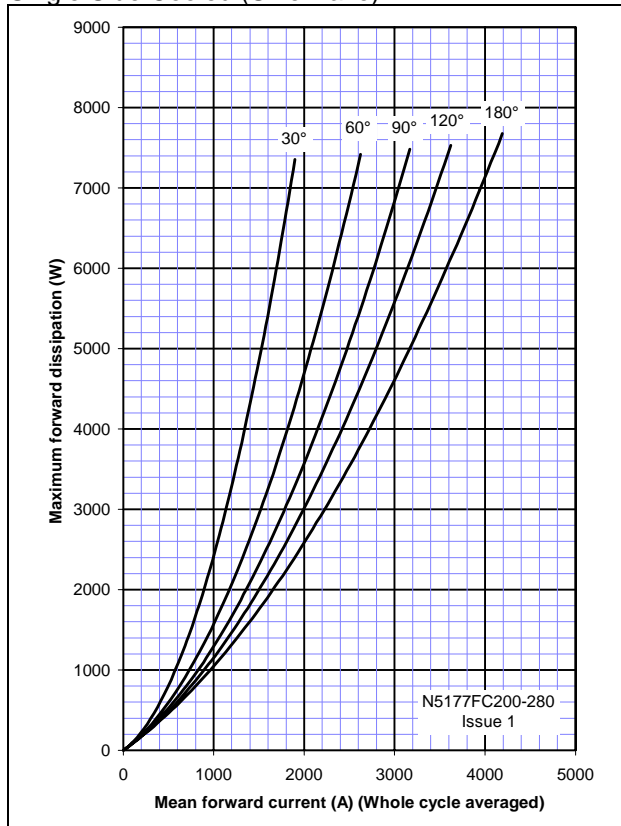


Figure 14 – On-state current vs. Heatsink temperature - Single Side Cooled (Sine wave)

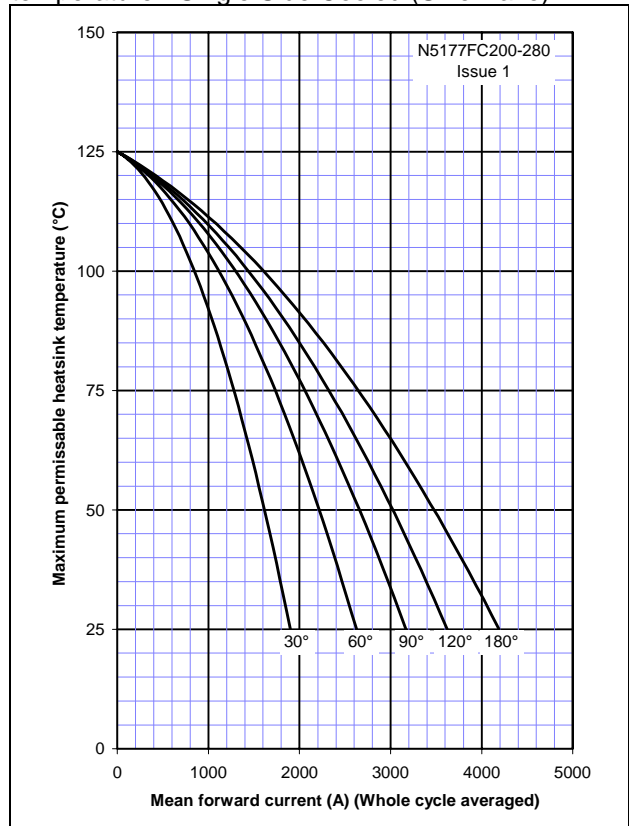


Figure 15 – On-state current vs. Power dissipation – Single Side Cooled (Square wave)

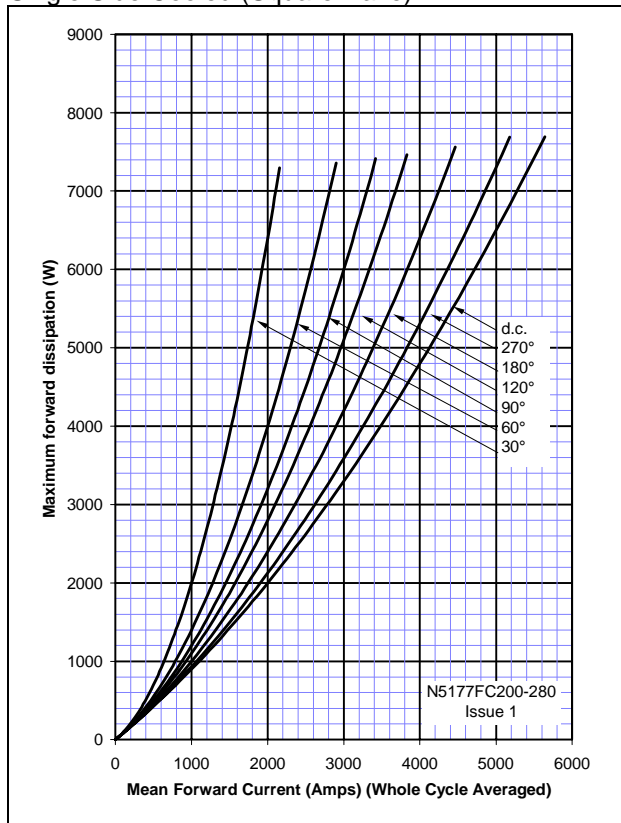


Figure 16 – On-state current vs. Heatsink temperature - Single Side Cooled (Square wave)

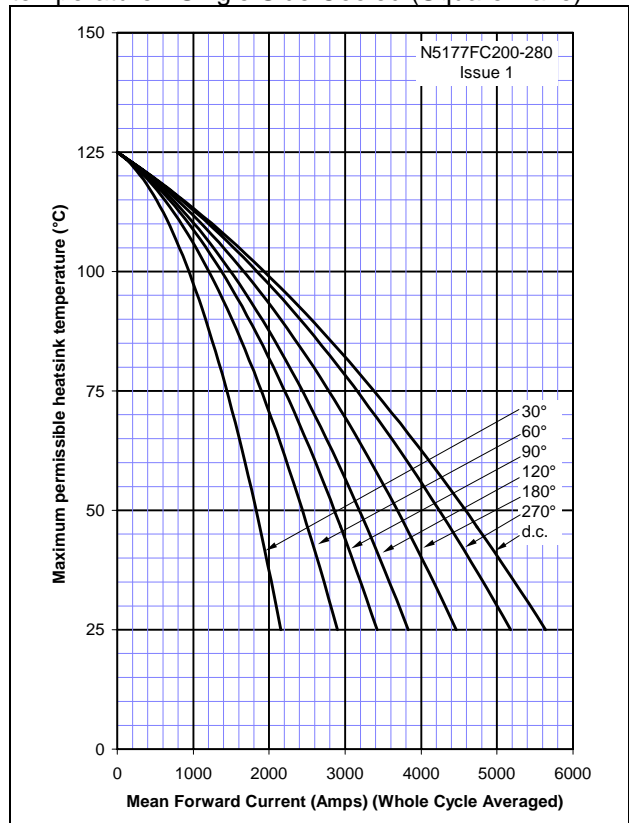
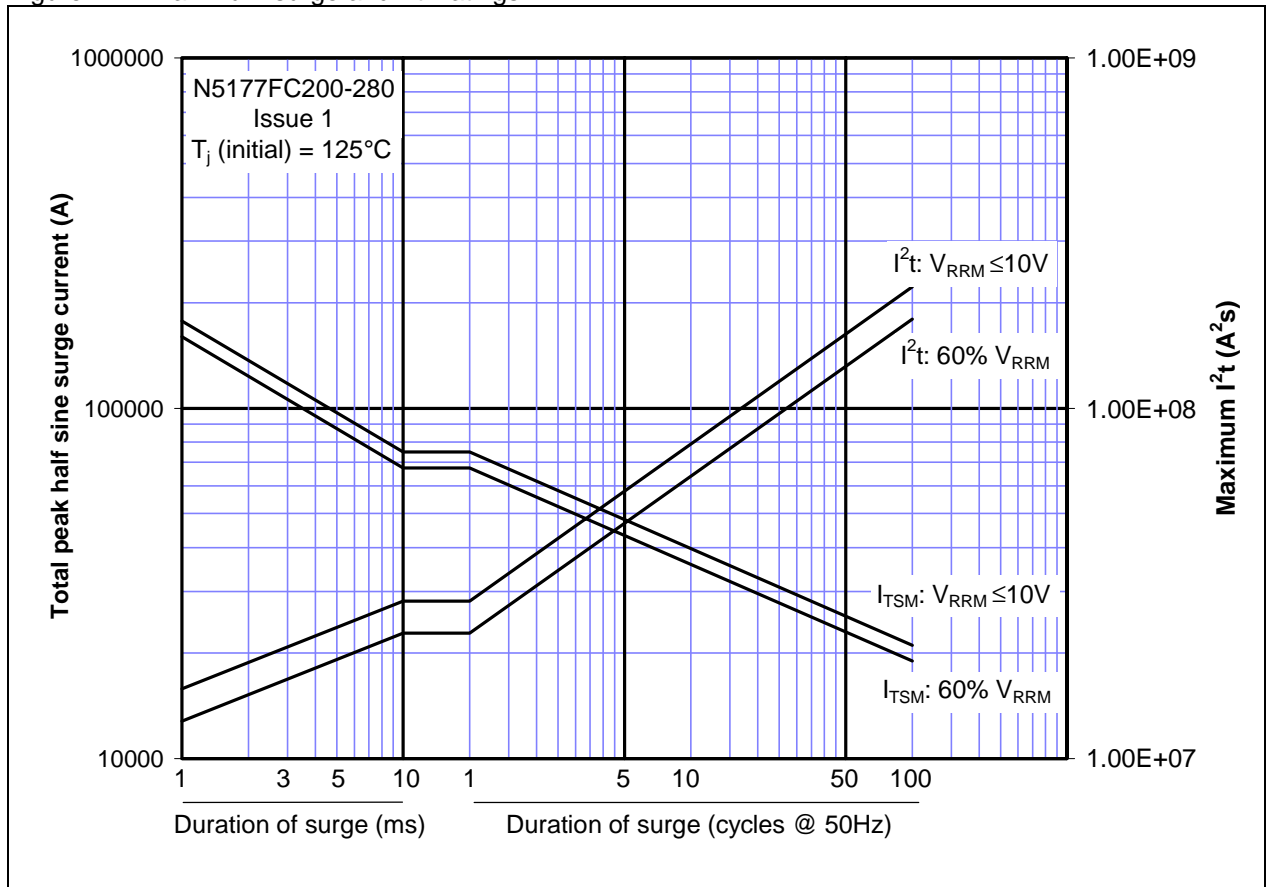
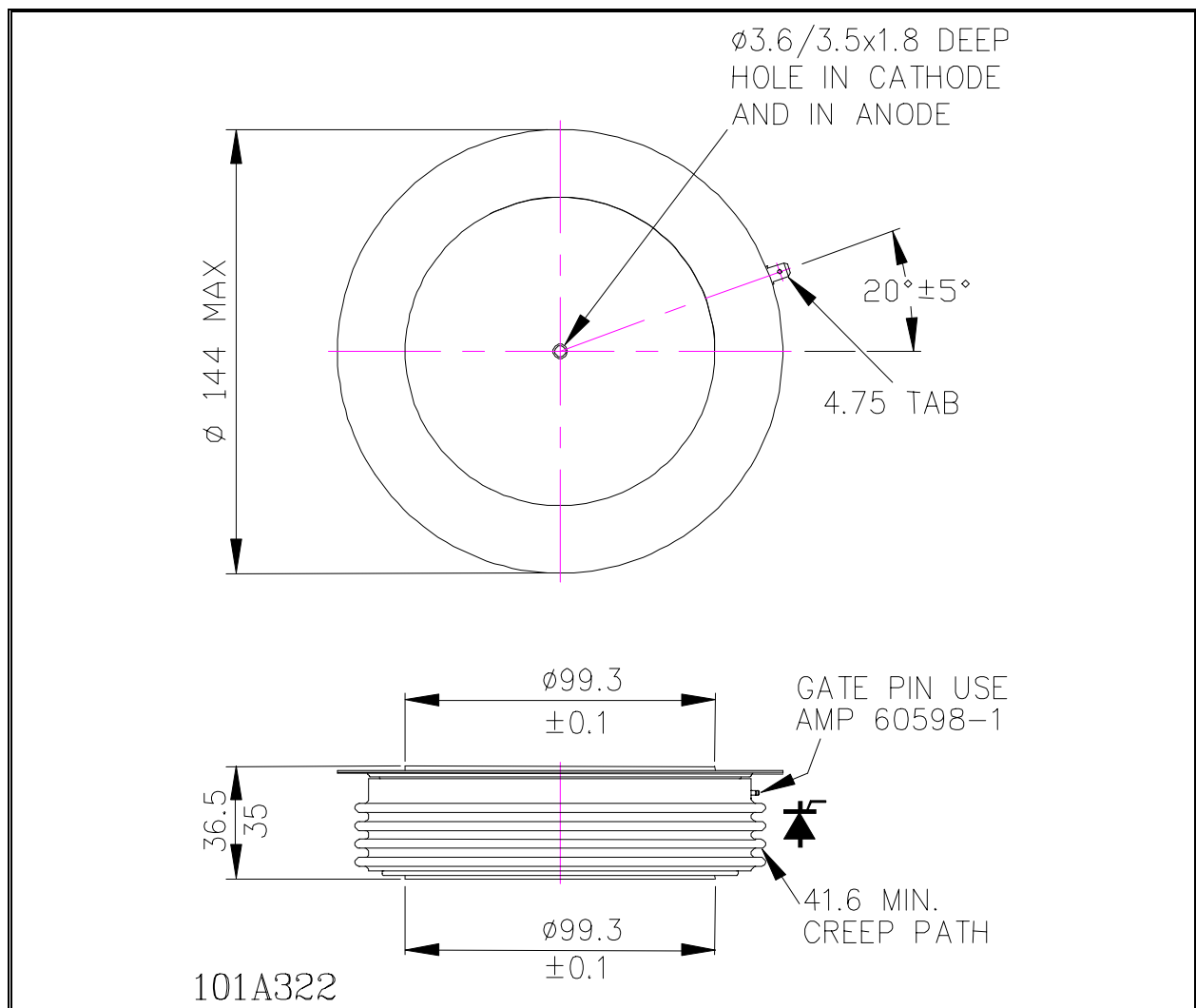


Figure 17 – Maximum surge and I^2t Ratings



Outline Drawing & Ordering Information



| ORDERING INFORMATION | | (Please quote 10 digit code as below) | |
|----------------------|--------------------|---------------------------------------|--------------------------|
| N5177 | FC | ◆◆ | 0 |
| Fixed Type Code | Fixed Outline Code | Voltage Code 20-28 | Fixed turn-off time code |

Typical order code: N5177FC200 – 2000V V_{DRM} , V_{RRM} , 1000V/ μ s dv/dt, 36.5mm clamp height capsule.

WESTCODE

UK: Westcode Semiconductors Ltd.
 P.O. Box 57, Chippenham, Wiltshire, England. SN15 1JL.
 Tel: +44 (0) 1249 444524 Fax: +44 (0) 1249 659448
 E-Mail: WSL.sales@westcode.com

USA: Westcode Semiconductors Inc.
 3270 Cherry Avenue, Long Beach, California 90807
 Tel: +1 (562) 595 6971 Fax: +1 (562) 595 8182
 E-Mail: WSI.sales@westcode.com

Internet: <http://www.westcode.com>

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